

 <p><b>Not Actual Photo</b> YIC International Co., Limited.</p>	<h2 style="color: red;">STB26N60M2</h2>	
	<b>Hersteller-Teilenummer:</b>	STB26N60M2
<b>Hersteller / Marke:</b>	STMicroelectronics	
<b>Teil der Beschreibung:</b>	MOSFET N-CHANNEL 600V 20A D2PAK	
<b>Datenblätter:</b>	<a href="#">1.STB26N60M2.pdf</a> <a href="#">2.STB26N60M2.pdf</a>	
<b>RoHs Status:</b>	Bleifrei / RoHS-konform	
<b>Lagerzustand:</b>	New original, 3633 pcs Stock Available.	
<b>Liefern von:</b>	Hong Kong	
<b>Versandweg:</b>	DHL/Fedex/TNT/UPS/EMS	

Image may be representation.  
See specs for product details.

### Spezifikationen

Artikelnummer	STB26N60M2
Hersteller	STMicroelectronics
Beschreibung	MOSFET N-CHANNEL 600V 20A D2PAK
Kategorie	<a href="#">Diskrete Halbleiterprodukte</a> > <a href="#">Transistoren-FETs</a> ,
Teilstatus	3633 pcs Stock
VGS (th) (Max) @ Id	4V @ 250µA
Vgs (Max)	±25V
Technologie	MOSFET (Metal Oxide)
Supplier Device-Gehäuse	D2PAK
Serie	MDmesh™ M2
Rds On (Max) @ Id, Vgs	165 mOhm @ 10A, 10V
Verlustleistung (max)	169W (Tc)
Verpackung	Cut Tape (CT)
Verpackung / Gehäuse	TO-263-3, D <sup>2</sup> Pak (2 Leads + Tab), TO-263AB
Andere Namen	497-17546-1
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Feuchtigkeitsempfindlichkeitsniveau (MSL)	1 (Unlimited)
Hersteller Standard Vorlaufzeit	42 Weeks
Bleifreier Status / RoHS-Status	Lead free / RoHS Compliant
Eingabekapazität (Ciss) (Max) @ Vds	1360pF @ 100V
Gate Charge (Qg) (Max) @ Vgs	34nC @ 10V
Typ FET	N-Channel
FET-Merkmal	-
Antriebsspannung (Max Rds On, Min Rds On)	10V
Drain-Source-Spannung (Vdss)	600V
detaillierte Beschreibung	N-Channel 600V 20A (Tc) 169W (Tc) Surface Mount
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	20A (Tc)

### Sie können auch interessiert

sein:  <b>STB25NM60N MOS</b> ST ST TO263	 <b>STB25NM60N-1</b> STMicroelectronics MOSFET N-CH 600V 21A I2PAK	 <b>STB25NM60ND</b> STMicroelectronics MOSFET N-CH 600V 21A D2PAK	 <b>STB26NM60ND</b> STMicroelectronics MOSFET N-CH 600V 21A D2PAK
 <b>STB25NM60N B25NM60N</b> ST ST TO-263	 <b>STB270N04</b> ST STB270N04 ST	 <b>STB270N04-1</b> ST STB270N04-1 ST	 <b>STB26NM60N</b> STMicroelectronics MOSFET N-CH 600V 20A D2PAK

### STB26N60M2 Zugehöriges

Mehr

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